









	<h2 style="color: red;">NSBC114EDXV6T1G</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">NSBC114EDXV6T1G</a>
	<b>Hersteller / Marke:</b>	<a href="#">AMI Semiconductor / ON Semiconductor</a>
	<b>Teil der Beschreibung:</b>	TRANS 2NPN PREBIAS 0.5W SOT563
<b>Datenblätter:</b>	 <a href="#">NSBC114EDXV6T1G.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 97045 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

### Spezifikationen

Teilenummer	<a href="#">NSBC114EDXV6T1G</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	TRANS 2NPN PREBIAS 0.5W SOT563
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-bipolare</a>
Teilstatus	97045 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	500mW
Verpackung / Gehäuse	SOT-563, SOT-666
Supplier Device-Gehäuse	SOT-563
Transistor-Typ	2 NPN - Pre-Biased (Dual)
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	250mV @ 300µA, 10mA
Strom - Collector Cutoff (Max)	500nA
DC Stromgewinn (HFE) (Min) @ Ic, VCE	35 @ 5mA, 10V
Frequenz - Übergang	-
Widerstand - Base (R1) (Ohm)	10k
Widerstand - Emitter-Basis (R2) (Ohm)	10k
Verpackung	Tape & Reel (TR)

NSBC114EDXV6T1G ist neu im Original, Suche NSBC114EDXV6T1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NSBC114EDXV6T1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NSBC114EDXV6T1G: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NSBC113EPDXV6T1G</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP SOT563</p>	 <p><b>NSBC114EDXV6T5G</b> AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.5W SOT563</p>	 <p><b>NSBC114EF3T5G</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 254MW SOT1123</p>	 <p><b>NSBC114EPDXV6T1G</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP SOT563</p>
 <p><b>NSBC114EPDXV6T1</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP SOT563</p>	 <p><b>NSBC114EDP6T5G</b> AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.408W SOT963</p>	 <p><b>NSBC113EPDXV6T1</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP SOT563</p>	 <p><b>NSBC113EF3T5G</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS DUAL NPN</p>

### heiße Teile

Mehr

7MBP200KA060	CGA5L3X8R1E225K160AE	CY7C1250KV18-400BZXC	DD285N160K	FZT869TA
LM385B-1.2	MAX8614BETD+T	NSB1706DMW5T1G	NSB4904DW1T1G	NSB8JT-E3/31
NSB9435T1	NSB9435T1G	NSBA114EDP6T5G	NSBA114EDXV6T1	NSBA114YDXV6T1
NSBA123JDXV6T1	NSBA123JDXV6T1G	NSBA123JDXV6T5G	NSBA143TDXV6T1G	NSBA144EDP6T5G
NSBC114EDXV6T1	NSBC114EPDXV6T1G	NSBC114EPDXV6T5	NSBC114TDXV6T1	NSBC114YDP6T5G
NSBC114YDXV6T1	NSBC114YDXV6T1G	NSBC114YDXV6T5	NSBC114YDPXV6T1	NSBC115EDXV6T1
NSBC123JDXV6T1	NSBC123JPDV6T1	NSBC123JPDV6T1G	NSBC124EPDXV6T1	NSBC124EPDXV6T5
NSBC124XPDXV6T1	NSBC143EDXV6T5	NSBC143ZPDV6T1G	NSBC143ZPDV6T5	NSBC144EDXV6T1
NSBC144EDXV6T1G	NSBC144EDXV6T5	NSBC144EDXV6T5G	NSBC144EPDXV6T1	NSBC144EPDXV6T1G
NTTFS4C13N	TISP1089AS	TPA6017A2PWPR	VE-JN3-IW	W1748LC220

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